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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



AMMC-6545

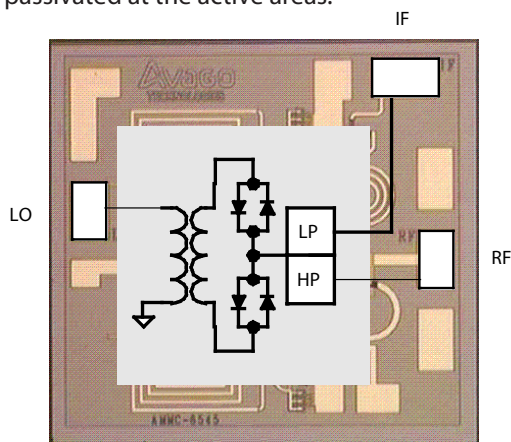
18 to 45 GHz Sub-Harmonic Mixer



Data Sheet

Description

Avago's AMMC-6545 is an easy-to-use broadband sub-harmonic mixer, with the LO injected at half the frequency of that required by a conventional mixer. MMIC includes an 180° balanced diode based mixer. The MMIC is fabricated using PHEMT technology. The sub-harmonic mixer is designed to be an easy-to-use component for any chip and wire application. Intended applications include microwave radios, 802.16, VSAT and satellite receivers. Since this one mixer can cover several bands, the AMMC-6545 can reduce part inventory. For improved reliability and moisture protection, the die is passivated at the active areas.



- Chip Size:** 885 μ m x 825 μ m
- Chip Size Tolerance:** $\pm 10 \mu$ m (± 0.4 mils)
- Chip Thickness:** 100 \pm 10 μ m (4 \pm 0.4 mils)
- Pad Dimensions:** 120 x 80 μ m (4.7 x 3.2 mils)

Features

- RF Frequency: 18-45GHz
- LO Frequency: 9-24GHz
- IF Frequency: DC-3GHz
- Suitable for Up and Down Conversion
- Diode Mixer

Typical Performance

- Conversion Loss: 11.0 \pm 1.5 dB
- 2*LO Leakage @ R port: -39 dBm
- 2*LO Leakage @ I port: -50 dBm
- L-R Isolation: 40 dB
- L-I Isolation: 36 dB
- IP₃ (@LO=+17dBm): +15 dBm
- LO Drive Power: +15 dBm
- LO Drive range (dBm): +12 to +20

Applications

- Microwave Radio systems
- Satellite VSAT, DBS Up/Down Link
- LMDS & Pt-Pt mmW Long Haul
- Broadband Wireless Access (including 802.16 and 802.20 WiMax)
- WLL and MMDS loops

Absolute Maximum Ratings^[1]

Symbol	Parameter/Condition	Units	Minimum	Maximum
Pin RF	CW Input Power to RF Port	dBm		25
T _b	Operating Backside Temp.	°C	-55	
T _{stg}	Storage Temp.	°C	-65	
T _{max}	Maximum Assembly Temp (60 sec max)	°C		260

Note:

1. Operation in excess of any one of these conditions may result in permanent damage to this device.

DC Specifications/Physical Properties^[2]

1. Operation in excess of any of these conditions may result in permanent damage to this device. The absolute maximum ratings for Pin were determined at an ambient temperature of 25°C unless noted otherwise.
2. Ambient operational temperature T_A=25°C unless noted.
3. Channel-to-backside Thermal Resistance (T_{channel} = 34°C) as measured using infrared microscopy. Thermal Resistance at backside temp. (T_B) = 25°C calculated from measured data.

AMMC-6545 Operating Conditions

Symbol	Parameters and Test Conditions	Units	Minimum	Typical	Maximum
RFfreq	RF Frequency	GHz	18		48
LOfreq	LO Frequency	GHz	9		24
IFfreq	IF Frequency	GHz	DC		3
LO	LO Drive Power	dBm	+12	+15	+22

AMMC-6545 RF Specifications

T_A = 25°C, Z_o = 50Ω, LO = +15 dBm, IF = 2GHz.

Symbol	Parameters	Frequency (GHz)	Units	Minimum	Typical	Maximum
CL	Conversion Loss ^[2]	RF=21GHz, LO=11.5GHz RF=23GHz, LO=12.5GHz RF=26GHz, LO=14GHz	dB		10	12
IIP3	Input Third Order Intercept ^[2]	RF=21GHz, LO=11.5GHz RF=23GHz, LO=12.5GHz RF=26GHz, LO=14GHz	dBm dBm dBm	11 9.5 8.5	13.5 10.3 10.9	
2LO-R	2LO-R Leakage	RF=21GHz, LO=10.5GHz RF=23GHz, LO=11.5GHz RF=26GHz, LO=13GHz	dBm dBm dBm		-45	-35
2LO-I	2LO-I Leakage	RF=21GHz, LO=10.5GHz RF=23GHz, LO=11.5GHz RF=26GHz, LO=13GHz	dBm dBm dBm		-50	
L-R	Isolation		dB		40	
L-I	Isolation		dB		36	

Notes:

1. Production RF tested at 21, 23 and 26GHz in up-converter configuration.
2. All tested parameters are guaranteed with ±0.5dB for CL and ±1.5dBm for IIP3 and 2LO-R leakage.

AMMC-6545 Typical Performance

$T_A = 25^\circ\text{C}$, $Z_0 = 50\Omega$, $LO = +15\text{ dBm}$, $IF = 1\text{GHz}$, $LO\text{ Power} = +15\text{ dBm}$ unless otherwise noted

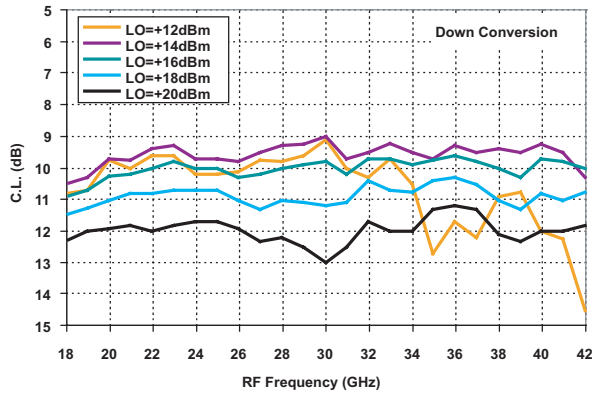


Figure 1. Down-Conversion Loss at LO=+12 to +20dBm
[LO Freq. = $(RF+IF)/2$, $IF=1\text{GHz}$].

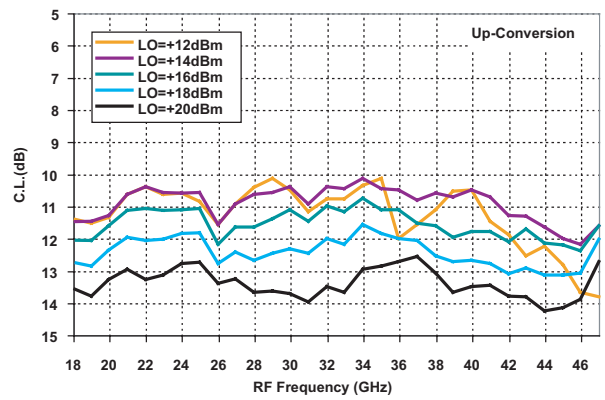


Figure 2. Up-Conversion Loss at LO=+13 to +20dBm
[LO Freq. = $(RF+IF)/2$, $IF=1\text{GHz}$].

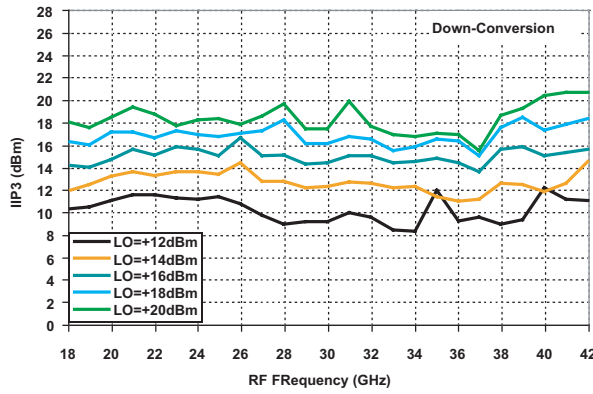


Figure 3. Down-Conversion IIP3 at LO=+12 to +20dBm
[LO Freq. = $(RF+IF)/2$, $IF=1\text{GHz}$].

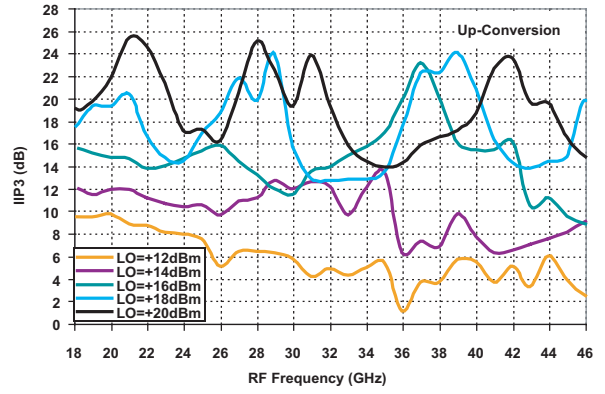


Figure 4. Up-Conversion IIP3 at LO=+12 to +20dBm
[LO Freq. = $(RF+IF)/2$, $IF=1\text{GHz}$].

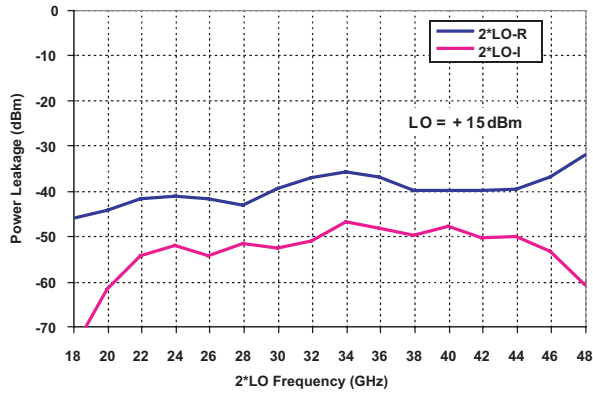


Figure 5. 2*LO-R and 2*LO-I Power Leakage @LO=+15dBm.

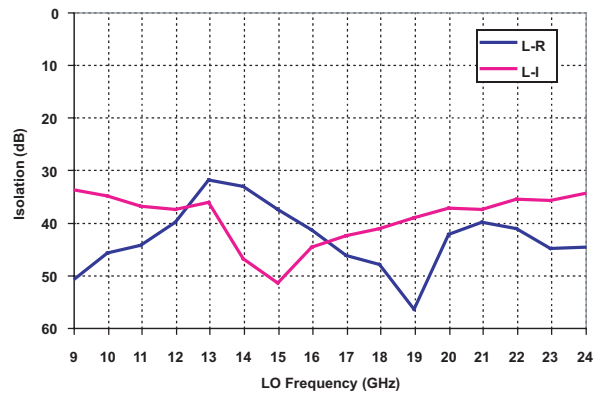


Figure 6. L-R and L-I Isolation @LO=+15dBm.

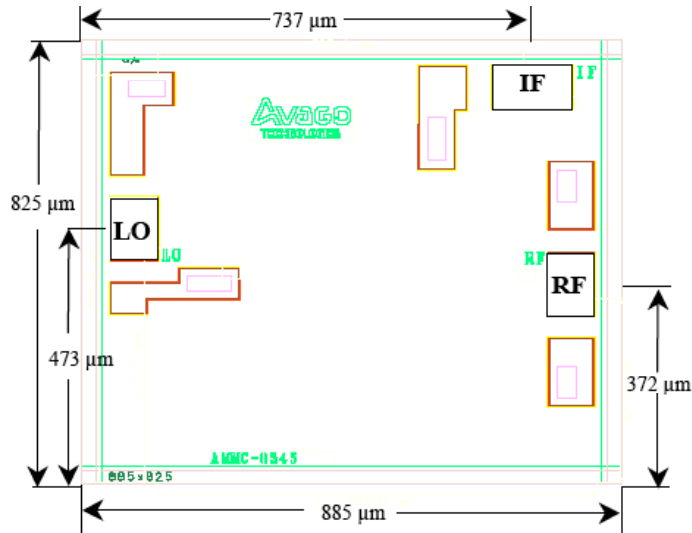


Figure 7. Die dimension details.

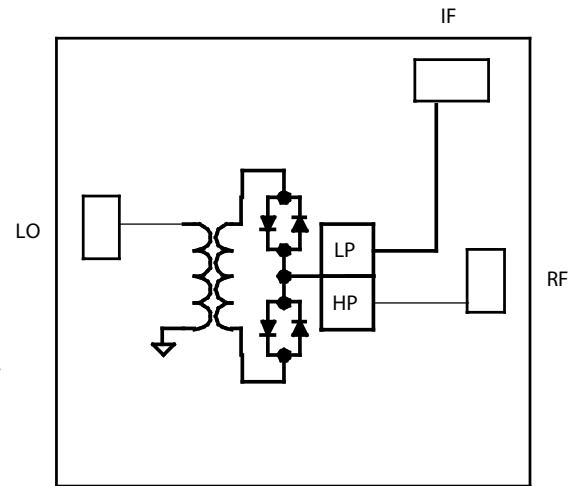


Figure 8. Simplified Schematic of the mixer.

AMMC-6545 Ordering Information

AMMC-6545-W10 = 10 devices per tray

AMMC-6545-W50 = 50 devices per tray

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